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Revised in February 2014

Very low power high stability low phase-noise miniature OCXO

Features

Miniature DIP8 sizes Very low power consumption (to 0.15W at +25°C) High frequency stability (to \pm 5 ppb over -40°C to 85°C) Very fast warming-up (to 15 s) Very low phase-noise level (-173 dBc/Hz, floor) Low aging (to \pm 2x10⁻¹⁰/day, \pm 3x10⁻⁸/year) Fundamental operation at up to 150 MHz

Typical Applications

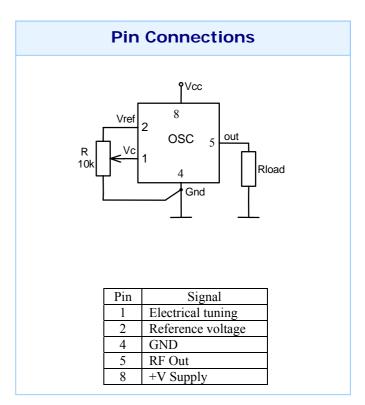
Portable Wireless Communications Mobile Test equipment Beacons & Rescue systems Battery Powered Applications



Description

The MXO37 series utilizes the internal heating resonator technology (IHR) with arrangement of the oven system together with the crystal plate inside the TO-8 vacuum holder. Such approach results in radical reduction of the OCXO sizes, power consumption and warm-up time. Compared with the basic MXO37/8 series the new model contains improved oscillator circuitry providing operation at higher fundamental frequencies at substantially better temperature stability and lower phasenoise level. The MXO37/8P is excellent solution for various portable or/and battery fed applications with elevated requirements to frequency stability and phase-noise of the OCXO.

Physical Dimensions MXO37/8P MXO37/8PS MXO37/8PS



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Specification

Very low power high stability low phase-noise miniature OCXO

Parameter Sym.		Sym.	Conditions		Value		Unit	Note
	Sym			Min. Typ. Max.		1	- 1000	
Frequency range f ₀		f_0		8		150	MHz	Fundamental operation
RF outp								
Load				10			kOhm	
HCMOS						15	pF	
(TTL) H-level voltage		V_{H}		3.8			V	
option	L-level voltage	$V_{\rm L}$				0.4	V	
	Duty cycle			45		55	%	
	Rise/Fall time					10	ns	For 10MHz operational Frequency.
Sine-	Level	L		+6	+8	+10	dBm	
wave	Load	$R_{\rm L}$			50		Ohm	
option	Harmonics level					-25	dBc	
Sub-harm	onics level				none			
Power su			1				I	<u> </u>
Voltage	рріу	V _{cc}		4.75	5.0	5.25	V	3.3V available
Voltage		v cc		7.75	3.0	3.23	'	3.5 v avanable
Power co	onsumption		Warm-up state		0.7		W	
1 OWCI CC	msumption		Steady state, +25°C		0.15		W	
Warm-up	n time	t _{up}	to $\Delta f/f=1e-7$, at $+25$ °C	15	45		s	ref. to frequency after 10 min
	cy control	cup	to 21/1 10-7, at +23 C	13	15		5	ren to frequency after 10 min
		V _c	V _{cc} =5 V	0		4.2	V	Tuning slope - positive
Control voltage range V _c		V c	$V_{cc}=3.3 \text{ V}$	0		2.8	v	(standard option)
Tuning range			V 66 3.3 V	±0.5	±1	2.0	ppm	(Standard Option)
		V _{ref}	V _{cc} =5 V	4.1	4.2	4.3	V	
		101	$V_{cc}=3.3 \text{ V}$	2.7	2.8	2.9	V	
Frequenc	cy stability							•
vs. tempe			-40°C to +85°C, ref 25°C			±5	ppb	See chart below
vs. supply voltage			ref Vcc typ.		±2		ppb	
vs. accele			Worst direction	±0.5		±1	ppb/G	
SSB Phas			1 Hz	-100	-95		dBc/Hz	For 10 MHz operational
DDD I IIa.	oc noise		10 Hz	-130	-125		ube/112	frequency.
			100 Hz	-150	-145		1	1-1-1-1
			1 kHz	-160	-155		1	
			10 kHz	-170	-165		1	
			100 kHz	-173	-168			1
Allan variance			1 s		20		e-12	1
Aging	per day	İ	after 30 days of operation	1	±0.5		ppb	See chart below
88	first year	t			±0.05		ppm	1
Environt	nental, mechanical o	ondition	ne	1	±0.02	ı	_ rr	ı
	temperature range	Januaru	See chart below.					
			-60°C to +90°C					
Storage temperature range Humidity			Non-condensing 95%					
Mechanical shock			Per MIL-STD-202, 30G half sine pulse, 11ms					
Vibration			Per MIL-STD-202, 30G man sine puise, 11 ms Per MIL-STD-202, 10G swept sine 10 to 2000 Hz					
			Hand solder only – not reflow compatible. 260°C 10s (on pins)					
Soldering conditions			riand solder only – not reflow compatible. 200°C 10s (on pins)					

Ordering code

1	Packaging type			
Co	de	Case		
/8P		8 DIP		
/8PS		8 DIP SMD		

2 Te	Temperature range		
Code	Specification		
A	0°C50°C		
В	-10°C60°C		
C	0°C70°C		
D	-20°C70°C		
Е	-30°C70°C		
F	-40°C85°C		

3 Stability over temperature				
Code	Specification Temperature range code available			
		10 MHz	100 MHz	
XZ	±Xe-Z			
39	±3e-9	AB	-	
59	±5e-9	AF	-	
18	±1e-8	AF	A	
28	±2e-8	AF	AE	
58	±5e-8	AF	AF	
17	±1e-7	AF	AF	

4	Aging			
Code	Per day	First year	Frequency	
В	0.2 ppb	0.02 ppm		
Z	0.3 ppb	0.03 ppm		
C	0.5 ppb	0.05 ppm	Below 50 MHz	
D	1.0 ppb	0.1 ppm		
Е	1.5 ppb	0.15 ppm		
F	2.0 ppb	0.2 ppm		
G	3.0 ppb	0.3 ppm	Above 50 MHz	
Н	5.0 ppb	0.5 ppm		

5	Supply voltage			
Co	de	Specification		
3	;	3.3V±5%		
5	5	5V±5%		

6	Output			
Code	Specification			
T	HSMOS/TTL			
S	Sine-wave			

Deviation of the parameters is possible on customers' requirements.